

FJA4310

Audio Power Amplifier

- High Current Capability : I_C=10A
- Complement to FJA4210



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	200	V
V _{CEO}	Collector-Emitter Voltage	140	V
V _{EBO}	Emitter-Base Voltage	6	V
l _C	Collector Current (DC)	10	А
I _B	Base Current (DC)	1.5	А
P _C	Collector Dissipation (T _C =25°C)	100	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =5mA, I _E =0	200			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =50mA, R _{BE} =∞	140			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E=5mA, I_C=0$	6			V
I _{CBO}	Collector Cut-off Current	V _{CB} =200V, I _E =0			10	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB}=6V$, $I_{C}=0$			10	μΑ
h _{FE}	* DC Current Gain	V_{CE} =4V, I_{C} =3A	50		180	-1.19
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =5A, I _B =0.5A	444		0.5	V
C _{ob}	Output Capacitance	V _{CB} =10V, f=1MHz	J 1	250		pF
f _T	Current Gain Bandwidth Product	V _{CE} =5V, I _C =1A	THE	30	100	MHz

^{*} Pulse Test : PW=20µs

h_{FE} Classification

Classification	R	0	Y
h _{FE}	50 ~ 100	70 ~ 140	90 ~ 180



Typical Characteristics

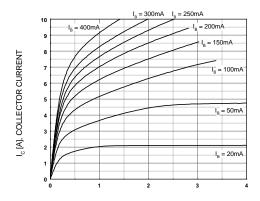


Figure 1. Static Characterstic

 V_{CE} [V], COLLECTOR-EMITTER VOLTAGE

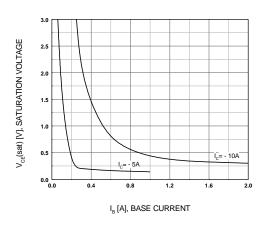


Figure 3. $V_{CE}(sat)$ vs. I_{B} Characteristics

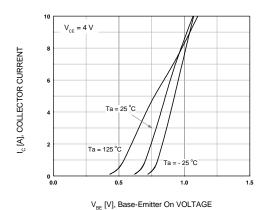


Figure 5. Base-Emitter On Voltage

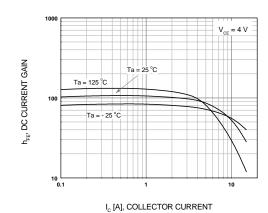


Figure 2. DC current Gain

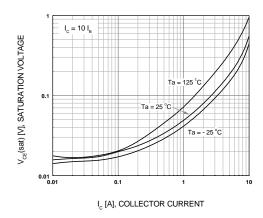
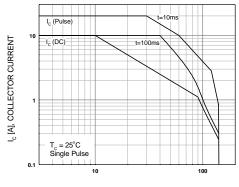


Figure 4. Collector-Emitter Saturation Voltage



 $V_{CE}^{}[V]$, COLLECTOR-EMITTER VOLTAGE

Figure 6. Forward Bias Safe Operating Area

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Typical Characteristics (Continued)

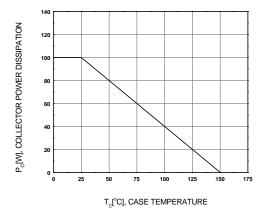
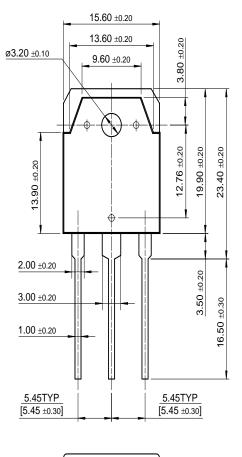
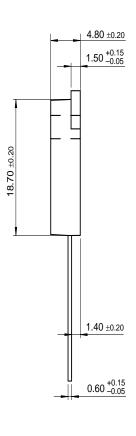


Figure 7. Power Derating

Package Demensions

TO-3P





Dimensions in Millimeters

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